

HD74SSTV16842

11-bit to 22-bit Buffer with SSTL_2 Inputs and Outputs

REJ03D0829-0200
(Previous: ADE-205-602A)
Rev.2.00
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Description

The HD74SSTV16842 is a 11-bit to 22-bit buffer designed for 2.3 V to 2.7 V Vcc operation and SSTL_2 data (A) inputs.

Features

- Supports SSTL_2 data inputs
- Flow through architecture optimizes PCB layout
- Ordering Information

Part Name	Package Type	Package Code (Previous code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74SSTV16842TEL	TSSOP-64 pin	PTSP0064KA-A (TTP-64DV)	T	EL (1,000 pcs / Reel)

Function Table

Input A	Output Y
L	L
H	H

H : High level

L : Low level

Pin Arrangement

Y11A	1	64	V _{DDQ}
Y10A	2	63	GND
GND	3	62	A11
Y9A	4	61	A10
Y8A	5	60	V _{CC}
V _{DDQ}	6	59	V _{DDQ}
GND	7	58	GND
Y7A	8	57	A9
Y6A	9	56	A8
Y5A	10	55	V _{DDQ}
GND	11	54	GND
Y4A	12	53	A7
Y3A	13	52	A6
Y2A	14	51	V _{DDQ}
GND	15	50	GND
Y1A	16	49	NC
Y11B	17	48	NC
V _{DDQ}	18	47	V _{DDQ}
Y10B	19	46	V _{CC}
Y9B	20	45	V _{REF}
Y8B	21	44	A5
GND	22	43	GND
Y7B	23	42	V _{DDQ}
Y6B	24	41	A4
Y5B	25	40	A3
GND	26	39	GND
V _{DDQ}	27	38	V _{DDQ}
Y4B	28	37	V _{CC}
Y3B	29	36	A2
GND	30	35	A1
Y2B	31	34	GND
Y1B	32	33	V _{DDQ}

(Top view)

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC} or V_{DDQ}	-0.5 to 3.6	V	
Input voltage ^{*1}	V_I	-0.5 to $V_{DDQ}+0.5$	V	
Output voltage ^{*1, 2}	V_O	-0.5 to $V_{DDQ}+0.5$	V	
Input clamp current	I_{IK}	± 50	mA	$V_I < 0$ or $V_I > V_{CC}$
Output clamp current	I_{OK}	± 50	mA	$V_O < 0$ or $V_O > V_{DDQ}$
Continuous output current	I_O	± 50	mA	$V_O = 0$ to V_{DDQ}
V_{CC} , V_{DDQ} or GND current / pin	I_{CC} , I_{DDQ} or I_{GND}	± 100	mA	
Maximum power dissipation at $T_a = 55^\circ\text{C}$ (in still air)	P_T	1	W	TSSOP
Storage temperature	T_{stg}	-65 to +150	$^\circ\text{C}$	

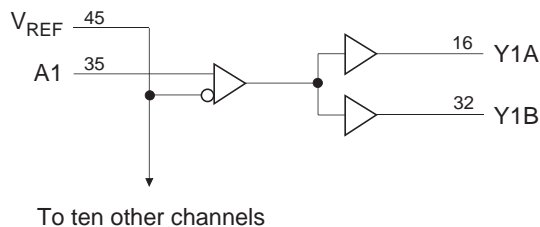
Notes: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
2. This current will flow only when the output is in the high state and $V_O > V_{DDQ}$.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit	Conditions
Supply voltage	V_{CC}	V_{DDQ}	2.5	2.7	V	
Output supply voltage	V_{DDQ}	2.3	2.5	2.7	V	
Reference voltage	V_{REF}	1.15	1.25	1.35	V	$V_{REF} = 0.5 \times V_{DDQ}$
Termination voltage	V_{TT}	$V_{REF}-40\text{ mV}$	V_{REF}	$V_{REF}+40\text{ mV}$	V	
Input voltage	V_I	0	—	V_{CC}	V	
AC high level input voltage	V_{IH}	$V_{REF}+310\text{ mV}$	—	—	V	A
AC low level input voltage	V_{IL}	—	—	$V_{REF}-310\text{ mV}$	V	A
DC high level input voltage	V_{IH}	$V_{REF}+150\text{ mV}$	—	—	V	A
DC low level input voltage	V_{IL}	—	—	$V_{REF}-150\text{ mV}$	V	A
High level output current	I_{OH}	—	—	-20	mA	
Low level output current	I_{OL}	—	—	20	mA	
Input transition rise or fall time	$\Delta t / \Delta v$	—	—	10	ns/V	
Operating temperature	T_a	0	—	70	$^\circ\text{C}$	

Logic Diagram



Electrical Characteristics

Item	Symbol	V _{CC} (V)	Min	Typ	Max	Unit	Test Conditions
Input diode voltage	V _{IK}	2.3	—	—	−1.2	V	I _{IN} = −18 mA
Output voltage	V _{OH}	2.3 to 2.7	V _{CC} −0.2	—	—	V	I _{OH} = −100 μA
		2.3	1.95	—	V _{DDQ}		I _{OH} = −16 mA
	V _{OL}	2.3 to 2.7	—	—	0.2		I _{OL} = 100 μA
		2.3	0	—	0.35		I _{OL} = 16 mA
Input current (All inputs)	I _{IN}	2.7	—	—	±5	μA	V _{IN} = 2.7 V or 0
Quiescent supply current	I _{CC} ^{*2}	2.7	—	—	45	mA	V _{IN} = V _{IH(AC)} or V _{IL(AC)} , I _O = 0
Dynamic operating per each data input	I _{CCD} ^{*2}	2.7	—	—	20	μA/ data input	V _I = V _{IH(AC)} or V _{IL(AC)} , One data input switching at 50% duty cycle.
Output high ^{*3}	r _{OH}	2.3 to 2.7	7	—	20	Ω	I _{OH} = −20 mA
Output low ^{*3}	r _{OL}	2.3 to 2.7	7	—	20	Ω	I _{OL} = 20 mA
r _{OH} − r _{OL} each separate bit ^{*3}	r _{O(Δ)}	2.5	—	—	4	Ω	I _O = 20 mA, T _a = 25°C
Input capacitance	C _{IN}	2.5 ^{*1}	2.5	—	3.5	pF	V _I = V _{REF} ±310 mV

Notes: 1. All typical values are at V_{CC} = 2.5 V, T_a = 25°C.

2. Total I_{CC} (max) = I_{CC} + {I_{CCD} (Data) × 11}

3. This is effective in the case that it did terminate by resistance.

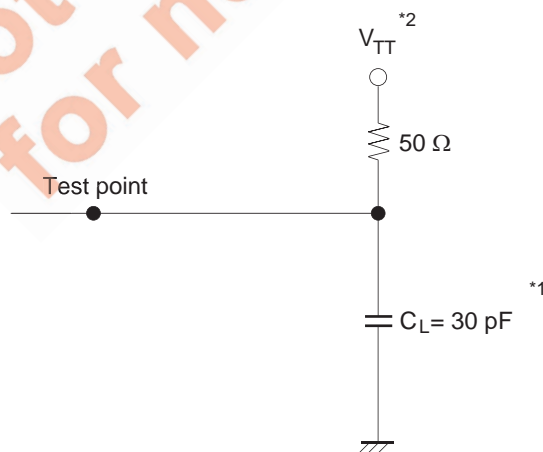
Switching Characteristics

$$V_{CC} = 1.8 \pm 0.15 \text{ V}$$

Item	Symbol	V _{CC} = 2.5 ± 0.2 V			Unit	FROM (Input)	TO (Output)
		Min	Typ	Max			
Propagation delay time ^{*1}	t _{PLH} t _{PHL}	1.6	—	2.8	ns	A	Y

Note: 1. This timing relationship is specified into test load (see waveforms – 1) with all of the outputs switching.

Test Circuit

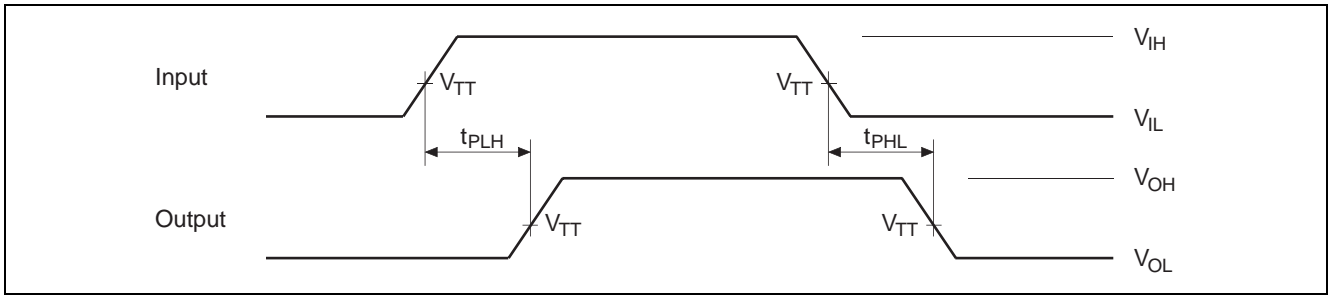


Notes: 1. C_L includes probe and jig capacitance.

2. V_{TT} = V_{REF} = V_{DDQ} × 0.5

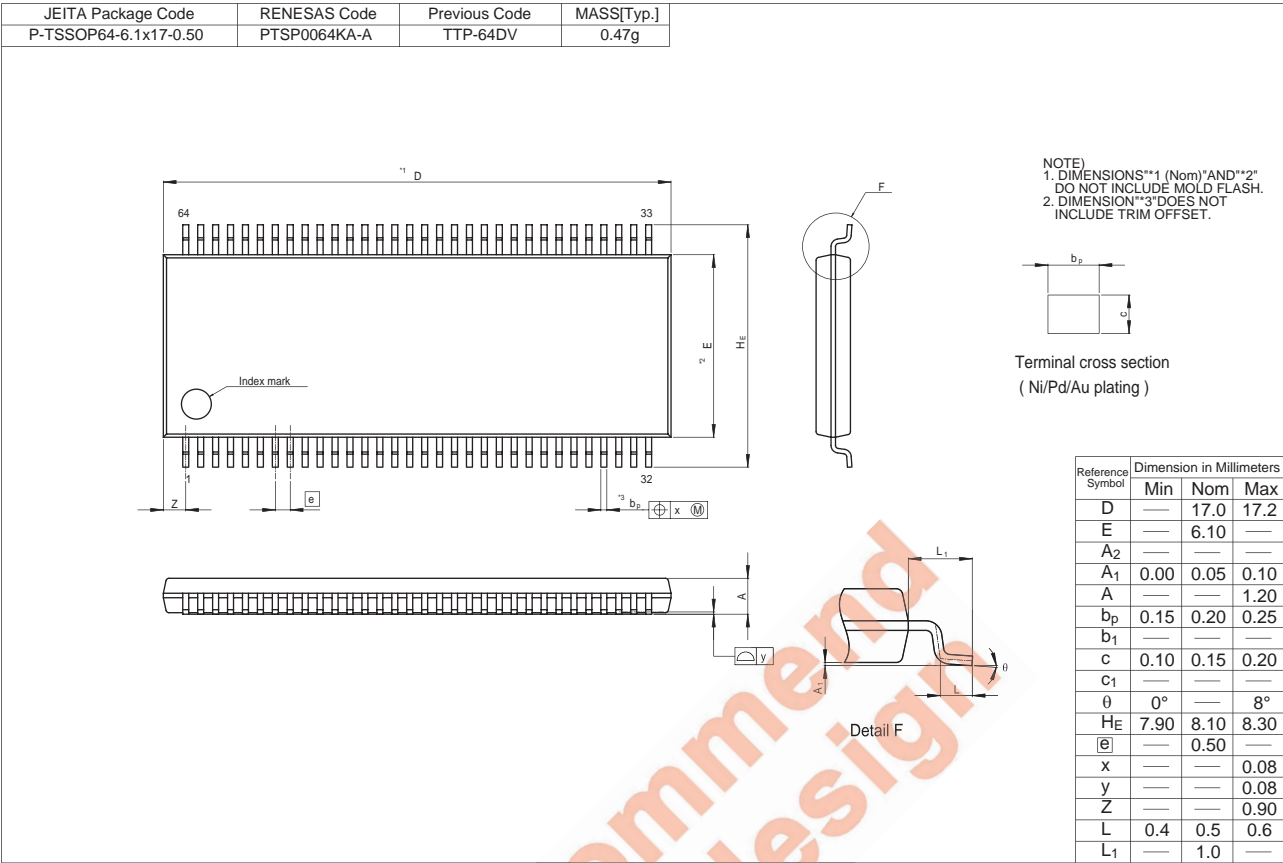
3. Input waveform : PRR ≤ 10 MHz, Z_o = 50 Ω,
Input slew rate = 1 V/ns ±20% (unless otherwise noted.)

Waveforms



Not recommend
for new design

Package Dimensions



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